

3.3V CMOS 18-BIT REGISTERED TRANSCEIVER WITH 3-STATE OUTPUTS, 5 VOLT TOLERANT I/O, BUS-HOLD

IDT74LVCHR16501A

FEATURES:

- Typical tsk(0) (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015;
 > 200V using machine model (C = 200pF, R = 0)
- 0.635mm pitch SSOP, 0.50mm pitch TSSOP and 0.40mm pitch TVSOP packages
- Extended commercial range of -40°C to +85°C
- $VCC = 3.3V \pm 0.3V$, Normal Range
- Vcc = 2.7V to 3.6V, Extended Range
- CMOS power levels (0.4µW typ. static)
- All inputs, outputs and I/O are 5 Volt tolerant
- Supports hot insertion

Drive Features for LVCHR16501A:

- Balanced Output Drivers: ±12mA
- Low switching noise

APPLICATIONS:

- 5V and 3.3V mixed voltage systems
- · Data communication and telecommunication systems

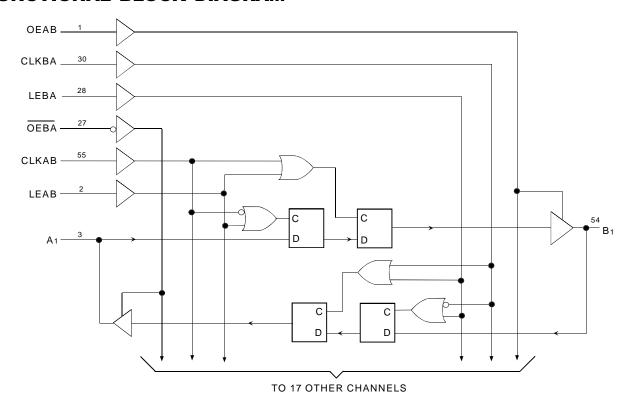
DESCRIPTION:

The LVCHR16501A 18-bit registered transceiver is built using advanced dual metal CMOS technology. This high-speed, low power 18-bit registered bus transceiver combines D-type latches and D-type flip-flops to allow data flow in transparent, latched, and clocked modes. Data flow in each direction is controlled by output-enable (OEAB and $\overline{\text{OEBA}}$), latch enable (LEAB and LEBA) and clock (CLKAB and CLKBA) inputs. For A-to-B data flow, the device operates in transparent mode when LEAB is high. When LEAB is low, the A data is latched if CLKAB is held at a high or low logic level. If LEAB is low, the A bus data is stored in the latch/flip-flop on the low-to-high transition of CLKAB. OEAB performs the output enable function on the B port. Data flow from B port to A port is similar but requires using $\overline{\text{OEBA}}$, LEBA and CLKBA. Flow-through organization of signal pins simplifies layout. All inputs are designed with hysteresis for improved noise margin.

The LVCHR16501A has series resistors in the device output structure which will significantly reduce line noise when used with light loads. This driver has been developed to drive $\pm 12mA$ at the designated thresholds.

The LVCHR16501A has "bus-hold" which retains the inputs' last state whenever the input goes to a high impedance. This prevents floating inputs and eliminates the need for pull-up/down resistors.

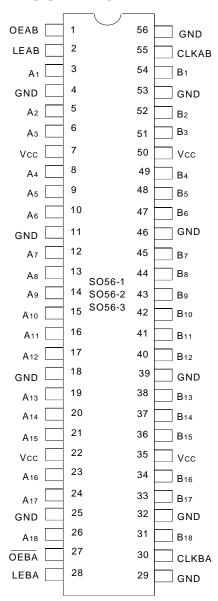
FUNCTIONAL BLOCK DIAGRAM



EXTENDED COMMERCIAL TEMPERATURE RANGE

OCTOBER 1999

PIN CONFIGURATION



SSOP/ TSSOP/ TVSOP TOP VIEW

PIN DESCRIPTION

Pin Names	Description
OEAB	A-to-B Output Enable Input
OEBA	B-to-A Output Enable Input (Active LOW)
LEAB	A-to-B Latch Enable Input
LEBA	B-to-A Latch Enable Input
CLKAB	A-to-B Clock Input
CLKBA	B-to-A Clock Input
Ax	A-to-B Data Inputs or B-to-A 3-State Outputs(1)
Вх	B-to-A Data Inputs or A-to-B 3-State Outputs ⁽¹⁾

NOTE:

 These pins have "Bus-hold". All other pins are standard inputs, outputs, or I/Os.

ABSOLUTE MAXIMUM RATINGS (1)

Symbol	Description	Max.	Unit
VTERM	Terminal Voltage with Respect to GND	- 0.5 to +6.5	V
Tstg	Storage Temperature	- 65 to +150	°C
Іоит	DC Output Current	- 50 to +50	mA
lıĸ	Continuous Clamp Current,	- 50	mA
Іок	$V_1 < 0$ or $V_0 < 0$		
Icc	Continuous Current through	±100	mA
Iss	each Vcc or GND		

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NOTE:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

CAPACITANCE (TA = +25°C, f = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Тур.	Max.	Unit
CIN	Input Capacitance	VIN = 0V	4.5	6	pF
Соит	Output Capacitance	Vout = 0V	6.5	8	pF
CI/O	I/O Port Capacitance	VIN = 0V	6.5	8	pF

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NOTE:

1. As applicable to the device type.

FUNCTION TABLE (1, 2)

	Inp	Outputs		
OEAB	LEAB	CLKAB	Ах	Вх
L	Х	Χ	Χ	Z
Н	Н	Χ	L	L
Н	Н	Х	Н	Н
Н	L	1	L	L
Н	L	1	Н	Н
Н	L	L	Х	B(3)
Н	L	Н	Х	B ⁽⁴⁾

NOTES:

- 1. H = HIGH Voltage Level
 - L = LOW Voltage Level
 - X = Don't Care
 - Z = High Impedance
 - ↑ = LOW-to-HIGH Transition
- A-to-B data flow is shown. B-to-A data flow is similar but uses OEBA, LEBA, and CLKBA.
- Output level before the indicated steady-state input conditions were established.
- Output level before the indicated steady-state input conditions were established, provided that CLKAB was HIGH before LEAB went LOW.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: TA = -40°C to +85°C

Symbol	Parameter	Tesi	t Conditions	Min.	Typ. ⁽¹⁾	Max.	Unit
VIH	Input HIGH Voltage Level	Vcc = 2.3V to 2.7V		1.7	_	_	V
		Vcc = 2.7V to 3.6V		2	_	_	
VIL	Input LOW Voltage Level	Vcc = 2.3V to 2.7V		_	_	0.7	V
		Vcc = 2.7V to 3.6V		_	_	0.8	
Іін	Input Leakage Current	Vcc = 3.6V	VI = 0 to 5.5V	_	_	±5	μΑ
İIL							
lozh	High Impedance Output Current	Vcc = 3.6V	$V_0 = 0 \text{ to } 5.5V$	_	_	±10	μΑ
lozl	(3-State Output pins)						
loff	Input/Output Power Off Leakage	$Vcc = 0V$, $Vin or Vo \le 5.5$	V	_	_	±50	μA
Vik	Clamp Diode Voltage	Vcc = 2.3V, IIN = - 18mA		_	- 0.7	- 1.2	V
VH	Input Hysteresis	Vcc = 3.3V		_	100	_	mV
ICCL	Quiescent Power Supply Current	Vcc = 3.6V	Vin = GND or Vcc	_	_	10	μA
Іссн							
Iccz			$3.6 \le VIN \le 5.5V^{(2)}$	_	_	10	
Δlcc	Quiescent Power Supply	One input at Vcc - 0.6V	_	_	_	500	μA
	Current Variation	other inputs at Vcc or GND)				LVC Link

NOTES:

1. Typical values are at Vcc = 3.3V, +25°C ambient.

2. This applies in the disabled state only.

BUS-HOLD CHARACTERISTICS

Symbol	Parameter ⁽¹⁾		Test Conditions	Min.	Typ. ⁽²⁾	Max.	Unit
Івнн	Bus-Hold Input Sustain Current	Vcc = 3.0V	VI = 2.0V	- 75	_	_	μA
I BHL			VI = 0.8V	75	_	_	
Івнн	Bus-Hold Input Sustain Current	Vcc = 2.3V	VI = 1.7V	_	_	_	μA
I BHL			VI = 0.7V	_	_	_	
Івнно	Bus-Hold Input Overdrive Current	Vcc = 3.6V	VI = 0 to 3.6V	_	_	± 500	μA
I BHLO							LVC Lin

NOTES

1. Pins with Bus-hold are identified in the pin description.

2. Typical values are at Vcc = 3.3V, +25°C ambient.

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OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Cor	nditions ⁽¹⁾	Min.	Max.	Unit
Vон	Output HIGH Voltage	Vcc = 2.3V to 3.6V	IOH = - 0.1mA	Vcc - 0.2	_	V
		Vcc = 2.3V	IOH = -4mA	1.9	_	
			IoH = -6mA	1.7	_	
		Vcc = 2.7V	IOH = -4mA	2.2	_	
			IoH = -8mA	2	_	
		Vcc = 3.0V	IOH = -6mA	2.4	_	
			IOH = - 12mA	2	_	
Vol	Output LOW Voltage	Vcc = 2.3V to 3.6V	IoL = 0.1mA	_	0.2	V
		Vcc = 2.3V	IoL = 4mA	_	0.4	
			IoL = 6mA	_	0.55	
		Vcc = 2.7V	IoL = 4mA	_	0.4	
			IoL = 8mA	_	0.6	
		Vcc = 3.0V	I _{OL} = 6mA	_	0.55	
			IoL = 12mA	_	0.8	LVC Link

NOTE:

OPERATING CHARACTERISTICS, V_{CC} = 3.3V \pm 0.3V, T_{A} = 25°C

Symbol	Parameter	Test Conditions	Typical	Unit
CPD	Power Dissipation Capacitance per transceiver Outputs enabled	CL = 0pF, f = 10Mhz		pF
CPD	Power Dissipation Capacitance per transceiver Outputs disabled			pF

^{1.} VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate Vcc range. TA = - 40°C to +85°C.

SWITCHING CHARACTERISTICS (1)

				= 2.7V	Vcc = 3.3	3V ± 0.3V	
Symbol		Parameter	Min.	Max.	Min.	Max.	Unit
tphL	Propagation Dela	у	1.5	7	1.5	6	ns
tplh	Ax to Bx or Bx to	Ax					
tphl	Propagation Dela	у	1.5	8	1.5	7	ns
tplh	LEBA to Ax, LEA	B to Bx					
tphl	Propagation Dela	·	1.5	8	1.5	6.7	ns
tplh	CLKBA to Ax, CL	KAB to Bx					
tрzн	Output Enable Ti	me	1.5	8.2	1.5	7.2	ns
tpzl	OEBA to Ax, OEA	AB to Bx					
tрнz	Output Disable Ti	ime	1.5	8	1.5	7	ns
tplz	OEBA to Ax, OEA	AB to Bx					
tsu	Set-up Time, HIG	H or LOW	2.5	_	2.5	_	ns
	Ax to CLKAB, Bx	to CLKBA					
tн	Hold Time, HIGH	or LOW	0	_	0	_	ns
	Ax to CLKAB, Bx	to CLKBA					
tsu	Set-up Time	Clock	2.5	_	2.5	_	ns
	HIGH or LOW	LOW					
	Ax to LEAB,	Clock	2.5	_	2.5	_	ns
	Bx to LEBA	HIGH					
tн	Hold Time HIGH or LOW Ax to LEAB, Bx to LEBA		1.5	_	1.5	_	ns
tw	LEAB or LEBA Pulse Width HIGH		3	_	3	_	ns
tw	CLKAB or CLKBA	Pulse Width HIGH or LOW	3	_	3	_	ns
tsk(o)	Output Skew ⁽²⁾			_	_	500	ps

NOTES:

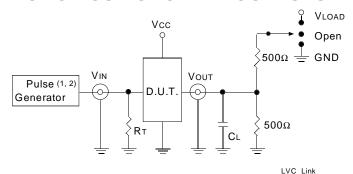
- 1. See test circuits and waveforms. $TA = -40^{\circ}C$ to $+85^{\circ}C$.
- 2. Skew between any two outputs of the same package and switching in the same direction.

TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS

Symbol	$Vcc^{(1)} = 3.3V \pm 0.3V$	$Vcc^{(1)} = 2.7V$	Vcc ⁽²⁾ = 2.5V ±0.2V	Unit
VLOAD	6	6	2 x Vcc	٧
VIH	2.7	2.7	Vcc	٧
VT	1.5	1.5	Vcc/2	٧
VLZ	300	300	150	mV
VHZ	300	300	150	mV
CL	50	50	30	pF

TEST CIRCUITS FOR ALL OUTPUTS



DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.

RT = Termination resistance: should be equal to Zo∪T of the Pulse Generator.

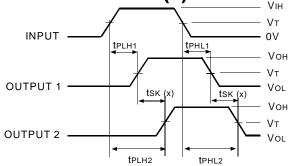
NOTES:

- 1. Pulse Generator for All Pulses: Rate \leq 10MHz; tr \leq 2.5ns; tr \leq 2.5ns.
- 2. Pulse Generator for All Pulses: Rate \leq 10MHz; tF \leq 2ns; tR \leq 2ns.

SWITCH POSITION

Test	Switch
Open Drain	VLOAD
Disable Low	
Enable Low	
Disable High	GND
Enable High	
All Other tests	Open
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OUTPUT SKEW - tsk (x)



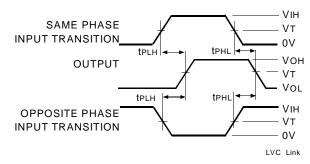
tSK(x) = |tPLH2 - tPLH1| or |tPHL2 - tPHL1|

NOTES:

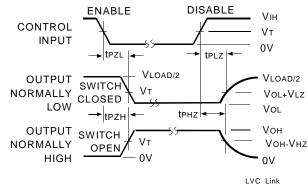
1. For tsk(o) OUTPUT1 and OUTPUT2 are any two outputs.

2. For tsk(b) OUTPUT1 and OUTPUT2 are in the same bank.

PROPAGATION DELAY



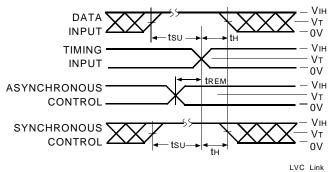
ENABLE AND DISABLE TIMES



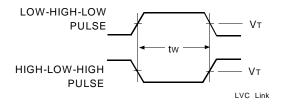
NOTE:

 Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

SET-UP, HOLD, AND RELEASE TIMES

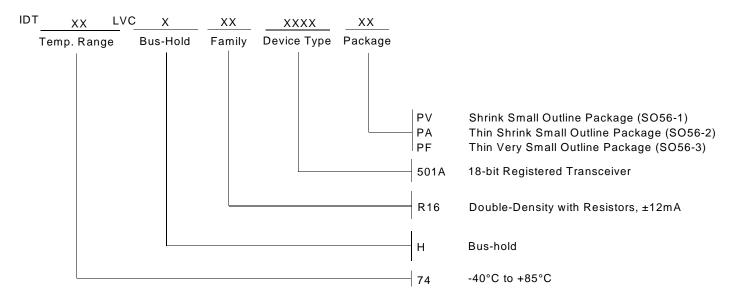


PULSE WIDTH



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ORDERING INFORMATION





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